

0.8 μ m SLD CAN AS8K215GY30M

The AS8K215GY30M is SLD (Super-Luminescent Diode) developed as incoherent light sources for various optical measurements including Optical Coherent Tomography (OCT). The device emits wide spectral incoherent light. High intensity in a narrow radiation angle makes high-efficient optical coupling to a single mode fiber.

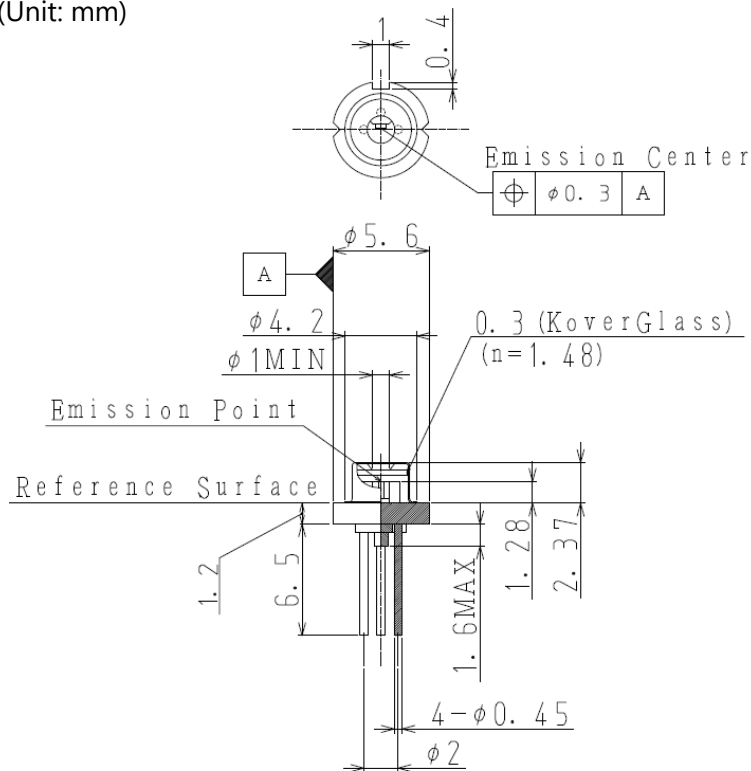
◆ FEATURES

- Φ 5.6 CAN package
- High optical output $P_o = 5$ mW
- Wide spectral half width $\Delta\lambda = 15$ nm (Typ.)
- Built-in monitor photo diode

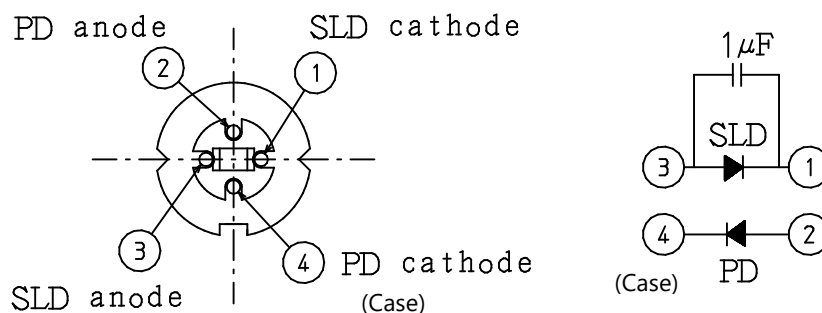
◆ APPLICATIONS

- Optical sensor / Optical encoder
- Optical Coherent Tomography (OCT)
- Optical measurement
- Substitute for high power LED

◆ DIMENSIONS (Unit: mm)



◆ PIN CONFIGURATION



◆ ABSOLUTE MAXIMUM RATINGS

Item	Symbol	Rating	Unit
SLD Reverse Voltage	V_R	2.0	V
Optical Output Power	P_o	6	mW
SLD Forward Current	I_F	120	mA
PD Reverse Voltage	V_{RD}	15	V
Operating Case Temperature	T_C	-20 to 70	°C
Storage Temperature *1	T_{stg}	-40 to 80	°C

*Excess over the absolute maximum ratings may lead to damage.

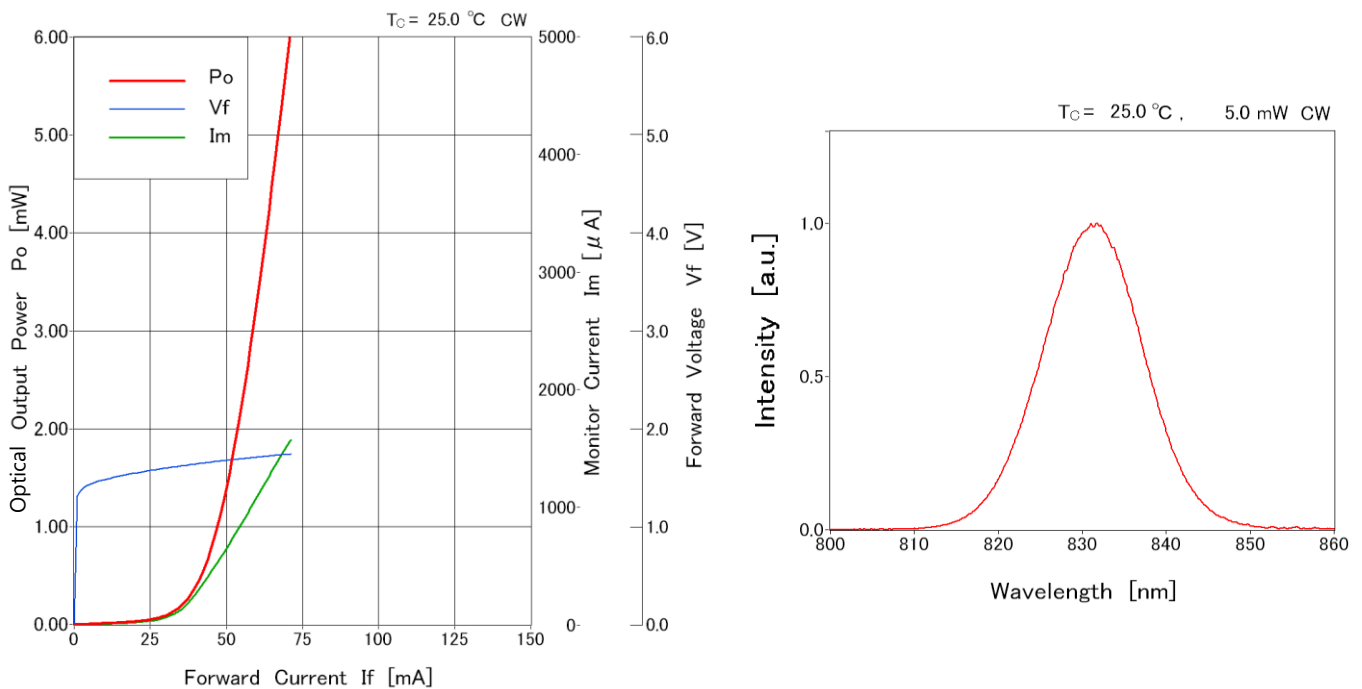
*1 No condensation

◆ OPTICAL AND ELECTRICAL CHARACTERISTICS ($T_C=25^\circ\text{C}$)

Item	Symbol	Test Condition	Min.	Typ.	Max.	Unit
SLD Forward Current	I_F	$P_o = 5 \text{ mW}$	-	70	100	mA
SLD Forward Voltage	V_F	$P_o = 5 \text{ mW}$	-	2.0	2.5	V
Center Wavelength	λ_c	$P_o = 5 \text{ mW}$	810	830	850	nm
Spectral Half Width	$\Delta\lambda$	$P_o = 5 \text{ mW}$	10	15	-	nm
Spectral Modulation	M_d	$P_o = 5 \text{ mW}$	-	2	10	%
PD Monitor Current	I_m	$P_o = 5 \text{ mW}, V_{RD} = 5 \text{ V}$	0.2	1.5	2.2	mA
Parallel Beam Divergence	$\theta_{//}$	$P_o = 5 \text{ mW}$	-	15	-	deg
Perpendicular Beam Divergence	θ_{\perp}	$P_o = 5 \text{ mW}$	-	45	-	deg

◆ TYPICAL CHARACTERISTICS

Optical Output Power / Monitor Current / Forward Voltage – Forward Current Characteristics / Emission Spectrum





CAUTION : Handle the fiber of the enclosed device(s) with extreme care ; glass fiber is subject to breakage if mishandled and permanent damage to the device may result. Do not pull the device by the fiber or protective sleeve.
Do not coil the fiber into a loop of than 30 mm in radius.

SEMICONDUCTOR LASER

DANGER

INVISIBLE LASER RADIATION
AVOID EYE OR SKIN EXPOSURE TO
DIRECT OR SCATTERED RADIATION

AVOID EXPOSURE
Invisible laser radiation is emitted from this aperture

OUTPUT POWER 500mW
WAVELENGTH 0.80 to 1.80 μm
CLASS IIIb LASER PRODUCT

Caution - use of controls or adjustments or performance of procedures other than those specified herein may result in hazardous radiation exposure.
This Product Complies with 21 CFR 1040.10 and 1040.11
Manufactured Anritsu Corp. 5-1-1 Onna, Atsugi-shi, Kanagawa, Japan

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